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Surface structure determination of silica single layer on Mo(112) by LEED

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Abstract

The atomic structure of silica single layer on a Mo(112) substrate was determined by means of low-energy electron diffraction analysis. The best-fit structure was consistent with findings of previous studies [Phys. Rev. Lett. 95 (2005) 076103 and Phys. Rev. Lett. 103 (2009) 017601]. The unit cell is $c(2\times 2)$ -Si₂O₅ and is composed of a two-dimensional network of SiO₄ tetrahedrons. The tetrahedrons incline slightly to fit the silica network on the Mo(112) surface while maintaining the ideal Si-O bond length. Since there are no dangling bonds in the silica network, the surface is very stable even in the atmosphere.

Keywords: Low energy electron diffraction (LEED); Molybdenum; silicon oxides

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1. Introduction

Thin oxide films have received great attention for their numerous applications to integrated circuits and as protective films against corrosion, and as supports for metal nanoparticles in catalysts and sensors. Their importance will be further increased with the miniaturization of devices. The atomic-level structure of thin-film oxides must be elucidated in order to determine their properties, and these structures have been studied for their technological importance and for the sake of fundamental sciences. Especially, thin-film oxides on metal surfaces have been studied as support materials of catalytic reactions [1]. Although silica layers were obtained on Mo(110) and Mo(100) surfaces [2,3], they could not be used as model cases because they were amorphous. On the other hand, Schroeder *et al.* obtained a crystalline silica layer on a Mo(112) surface, and it would be ideal as a support material for catalytic reactions [4-7]. Growth of crystalline silica thin layers on Ni(111), Pd(100) and Ru(0001) has also been reported [8-10], and many applications for these materials as model support materials, devices, sensors and so on have been expected. Moreover, crystalline silica single layers were obtained on SiC(0001) and SiC(000 $\bar{1}$) surfaces [11,12]. Their structures have been already determined and they are robust even in air.

Crystalline silica thin layers on Mo(112) have a $c(2\times 2)$ unit cell [4], and their surface structures have been studied by several methods. Chen *et al.* studied the surface using low-energy electron diffraction (LEED), high-resolution electron energy-loss spectroscopy (HREELS) and scanning tunneling microscopy (STM), and proposed an isolated SiO_4 model [13-15]. Weissenrieder and Todorva *et al.* proposed a network model using STM, infrared reflection absorption spectroscopy (IRAS), X-ray photoelectron spectroscopy (XPS) and density functional theory (DFT) calculation [16,17]. A similar network model was also proposed by Giordano *et al.* [18,19]. Recently, Seifert *et al.* solved the controversy between above two models using ion beam triangulation method [20,21]. The data clearly provided evidence for the network model. However, structural determination using diffraction methods has not yet been done. Quantitative LEED intensity analysis is one of the most powerful and reliable methods for surface structure determination; it has been used to determine many surface structures with good accuracy, *e. g.* 0.1 Å. In this study, we examined the Mo(112)- $c(2\times 2)$ -silica structure by means of LEED analysis. The determined structure model is again consistent with the network model proposed by Weissenrieder and Todorova *et al.*

2. Experiment

Experiments were carried out in an ultrahigh vacuum (UHV) chamber (the base pressure during experiments was better than 5×10^{-7} Pa) equipped with LEED optics (SPECTALEED, Omicron). A single-crystal Mo(112) disk (10 mm ϕ , 2 mm thick) was welded to a Ta wire (0.7 mm ϕ) for resistive heating. The sample was simultaneously heated by electron bombardment from a tungsten filament placed closed to the backside of the sample. The temperature was measured by a thermo spot sensor (FTZ6, Japan Sensor). First, the sample was cleaned by cycles of annealing in 1×10^{-5} Pa oxygen at 1200 K and flashing to 2200 K in UHV. A clear (1 \times 1) LEED pattern was observed as reported in Ref. 22. Secondly, the sample surface was oxidized for 10 min in 5×10^{-6} Pa oxygen at 850 K. Finally, silicon was deposited on the sample from a high-temperature Si wafer heated by direct resistive heating. The silicate film was prepared by Si deposition for 5 min in 5×10^{-5} Pa oxygen at 800 K, followed by annealing for 5 min at 1200 K in UHV. A clear c(2 \times 2) LEED pattern was observed after this treatment as previously reported in Ref. 4.

The LEED spot intensities were measured by a digital charge-coupled device camera with a computer-controlled data acquisition system [23]. For structural analysis, the intensity versus electron beam energy spectra [$I(E)$ curves] of the LEED spots were measured within an incident energy range of 50-400 eV. The summation of energy ranges of inequivalent $I(E)$ curves, ΔE , were 1647 and 2934 eV for clean Mo(112)-(1 \times 1) and c(2 \times 2)-silicate surfaces, respectively. A Barbieri-Van Hove symmetrized automated tensor LEED package was used to determine the atomic positions [24]. Thirteen phase shifts were used to represent atomic scattering. The dumping of incident electrons was represented by an imaginary part of the inner potential, V_{0i} , of -5.0 eV. Pendry's reliability factor (R_P) was used to direct the automated search algorithm [24,25]. The best agreement between experimental and theoretical $I(E)$ curves involved minimizing the R_P . Errors in the structural parameters were estimated from the variance of the R_P , $\Delta R = R_P (8|V_{0i}|/\Delta E)^{1/2}$ [25].

3. Results and Discussion

3.1. Structural determination of the clean Mo(112)-(1 \times 1) surface

First we examined the structure of the clean Mo(112)-(1 \times 1) surface. The LEED pattern of the clean Mo(112) surface is shown in Fig. 1(a). The structure had been determined

by Kolthoff *et al.* using LEED analysis and is an ideally truncated crystal surface [22]. The structure model is shown in Fig. 2. There is one mirror plane displayed by the dashed line. The unit cell is shown by a rectangle with side lengths of 4.45 Å and 2.73 Å. The bulk layer distance toward the $[11\bar{2}]$ direction is 1.28 Å. The surface perpendicular stacking has a 6-layer period with a 2-layer period toward the $[\bar{1}10]$ direction and a 3-layer period toward the $[11\bar{1}]$ direction.

The structural parameters obtained from this study are shown in Table 1. Pendry's reliability factor became 0.193 after relaxation of the interlayer distances. We used seven inequivalent beams, and the total energy range was 1647 eV. The calculated $I(E)$ curves agreed with the experimental $I(E)$ curves very well as shown in Fig. 3. The Debye temperatures were fitted to 150, 175, 250, 350, 450 and 450 K for each Mo layer from the surface topmost layer to the 6th layer, respectively. Interlayer distances calculated from Table 1 were 1.11, 1.35, 1.22, 1.32 and 1.27 Å from the surface and show a typical surface relaxation. This was also consistent with previous LEED analyses (1.09, 1.31, 1.26 and 1.29 Å from surface) [22]. The total energy range used in the previous study was 991 eV and the obtained R_p was 0.205. The present study had a larger total energy range (1647 eV) and a smaller R_p value (0.193).

3.2. Structural determination of the Mo(112)-c(2×2)-silica surface

The LEED pattern of the silica surface is shown in Fig. 1(b). A sharp c(2×2) pattern was observed as in previous studies after the sample treatment of silicon deposition, oxidation and annealing [4,13,17]. We have examined the isolated silica model, the network model and other possible models by LEED analysis. The eleven examined Mo(112)-c(2×2)-silica models are shown in Fig. 4. Every model has one mirror plane indicated by a dashed line. Model 1 is the network model proposed by Weissenrieder and Todorva *et al.* and models 2-6 are its derivative models. Oxygen atoms sit on a bridge site, a top site or a hollow site of the Mo interface layer for models 1, 2 and 3, respectively. The topmost silicate networks sit on oxygen atoms, and the oxygen atoms connect Mo and Si atoms with bent bonds. Models 4-6 are similar to models 1-3, respectively, but the oxygen atoms bridge Mo and Si atoms with almost straight bonds similar to the case of the silica layer on an SiC(0001) surface [11]. Model 7 is the isolated SiO₄ model proposed by Chen *et al.*, and models 8-11 are related models [13]. Model 8 and 10 have two or three SiO₄ units in their unit cells, respectively, and the SiO₄ units are connected with each other. Model 9 shows a dimer of two SiO₄ units sharing a corner oxygen. Model 11 resembles β quartz, in which one SiO₄ unit shares its

four corner oxygen atoms with four neighboring SiO_4 units. We used 14 inequivalent beams for LEED analysis. The obtained R_p values for the 11 models are shown in Table 2. Models 1 and 4 had small R_p values of 0.18 and 0.23, and other models had R_p values greater than 0.5. Model 1 and model 4 have similar structures, and they also have similar theoretical $I(E)$ curves. However, their R_p values have meaningful differences of 0.05 compared to the ΔR value of 0.02. The theoretical $I(E)$ curves for model 1 were plotted with the experimental $I(E)$ curves in Fig. 5 and they have quite nice agreement. Therefore, we concluded that model 1 is the correct model. It is consistent with the previous study using ion beam triangulation method [20,21]. The optimized best-fit model is shown in Fig. 6 and its structural parameters are listed in Table 3. The optimized Debye temperatures were 300, 300, 225, 300, 350, 400 and 450 K for O(1,1'), O(2), Si(1,1'), O(3,3'), Mo(1,1'), Mo(2,2') and Mo(3,3'), respectively.

The diamond in the top view of Fig. 6 shows the $c(2\times 2)$ unit cell. The topmost layer in the unit cell consists of three oxygen atoms and one silicon atom. Two oxygen atoms were equivalent (marked 1 and 1') but the other oxygen atom was inequivalent (marked 2). The oxygen atoms bind with two equivalent silicon atoms (marked 1 and 1') to form a two-dimensional hexagonal network. The silicon atoms connect with the second layer of oxygen atoms (marked 3 and 3'). As a result, each silicon atom has four bonds, and the SiO_4 units share the corner oxygen atoms. The second-layer oxygen atoms are located on the bridge site of the substrate Mo atoms (marked 1 and 1'). The structure of the Mo atoms is similar to the structure of clean Mo(112)-(1 \times 1), but the interlayer distances are different. The first and second interlayer distances are 1.21 and 1.34 Å, and these are much closer to the bulk value (1.28 Å) compared with the case of the clean surface (1.11 and 1.35 Å). It is reasonable that the surface covered by the silica layer and the surface relaxation becomes smaller than the clean surface.

3.3. Features of the Mo(112)- $c(2\times 2)$ - Si_2O_5 surface

The determined structure has no dangling bond in the silica layer and is composed of Si_2O_5 . The bond lengths and bond angles of the silica layer are listed in Table 4 and are calculated from the best-fit structural parameters. Corresponding values obtained from an α - SiO_2 crystal [26] and MoO_2 crystal [27], and previous results by first principles calculation [17] are also shown. Our results are very similar to the previous results by Todorova *et al.* The bond lengths are similar to the typical values in the bulk crystal. These results suggest the high stability of the Mo(112)- $c(2\times 2)$ - Si_2O_5 surface. Actually, we could observe clear $c(2\times 2)$ LEED patterns after we exposed the sample to air

without any treatment in the UHV chamber.

Similar network structures of silica or silicon oxynitride layers were reported on 6H-SiC(000 $\bar{1}$) and 6H-SiC(0001) substrates [11,12]. Their structural parameters have been determined by LEED analysis. They are also terminated by silica single layer networks. The Si-O bond lengths are 1.61-1.63 Å and the Si-O-Si bond angles are 141-146° and 180°. Though the bond lengths are quite similar to the case of the Mo surface, the bond angles are different. The topmost silica layer of the SiC substrate has a hexagonal unit cell, and the base of the SiO₄ tetrahedron is parallel to the surface. The unit cells of silica on SiC are ($\sqrt{3}\times\sqrt{3}$)R30° and hexagonal with a lattice constant of 5.35 Å. On the other hand, the SiO₄ tetrahedron on the Mo substrate inclines toward the [$\bar{1}$ 10] or [$\bar{1}$ 10] direction. The O(1,1') atoms come out to the vacuum and the O(2) atoms go down to the bulk. Since the O(3,3') atoms adsorb on the bridge site of the Mo(112), the SiO₄ tetrahedron is inclined and the Si-O-Si bond angles are changed from the typical values. The unit cell of silica on Mo is quasi-hexagonal with a lattice constant of 5.23 Å. While the size of silica on Mo is smaller than that of silica on SiC, the Si-O bond lengths are almost equal due to the incline of the tetrahedrons. Only the Mo(112) surface is suitable for the growth of silica among the Mo crystal surfaces. Other low-index Mo surfaces do not have suitable cells for the growth of silica layers. Very recently, the growth of a double-layer sheet silica model on an Ru(0001) surface was reported [10]. The lattice constant of the hexagonal Ru(0001)-(2×2) unit was 5.42 Å, and the size was suitable for the growth of similar silica network structures.

The STM images in the previous studies show chain-like features toward the [$\bar{1}\bar{1}1$] directions [15,17]. This is very consistent with our model. The SiO₄ tetrahedrons incline slightly, and the O(1,1') atoms protrude further than the O(2) atoms. As a result, the STM images might appear as stripes rather than a honeycomb. In the high-resolution STM images by Chen *et al.*, single or double spots appear in the unit cell depending on the sample bias voltages [15]. The double spots are difficult to explain by the hexagonal silica layer. However, we have two equivalent O(1,1') atoms and one inequivalent O(2) atom in the unit cell, and it is likely to have electronic states to be showing two spots in the unit cell.

4. Conclusion

We have reinvestigated the structure of a clean Mo(112) surface and silica single layer on a Mo(112) surface. The clean Mo(112) surface has a crystal truncated structure with large surface relaxation. The silica single layer has a two-dimensional network of SiO₄

tetrahedrons with a $c(2\times 2)$ - Si_2O_5 unit cell. The tetrahedrons incline slightly to fit the Mo(112) substrate and have ideal Si-O bond lengths. The silica layer has no dangling bonds and this makes the surface very stable.

Acknowledgements

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Figure captions

Fig. 1. LEED patterns of (a) Mo(112)-(1×1) clean surface and (b) Mo(112)-c(2×2)-silica surface.

Fig. 2. Top and side views of the Mo(112)-(1×1) clean surface.

Fig. 3. Experimental and theoretical $I(E)$ curves of the best-fit Mo(112)-(1×1) clean surface model.

Fig. 4. Top and side views of examined structure models of the Mo(112)-c(2×2)-silica.

Fig. 5. Experimental and theoretical $I(E)$ curves for the best-fit structural model of the Mo(112)-c(2×2)-Si₂O₅ surface.

Fig. 6. Top and side views of the best-fit Mo(112)-c(2×2)-Si₂O₅ surface (model 1).

Table 1. Structural parameters obtained for the best-fit Mo(112)-(1×1) clean surface model.

Table 2. Pendry's r -factors (R_p) for the models shown in Fig. 4.

Table 3. Structural parameters obtained for the best-fit Mo(112)-c(2×2)-Si₂O₅ surface (model 1).

Table 4. Summary of bond lengths and bond angles.

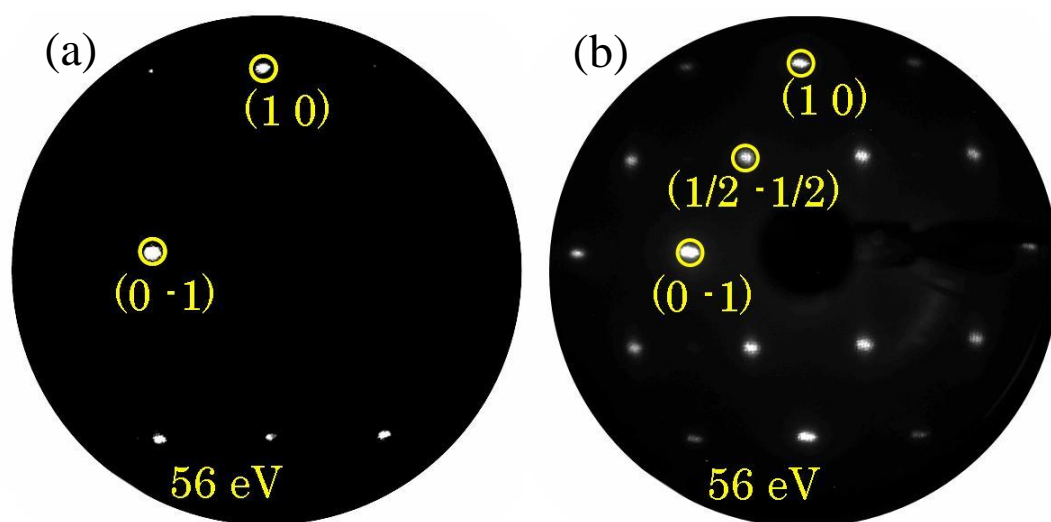


Fig. 1. LEED patterns of (a) Mo(112)-(1×1) clean surface and (b) Mo(112)-c(2×2)-silica surface.

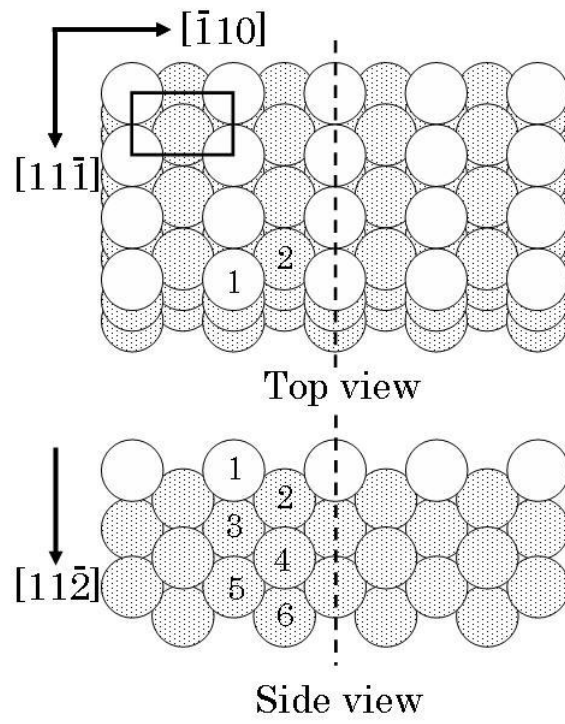


Fig. 2. Top and side views of the Mo(112)-(1x1) clean surface.

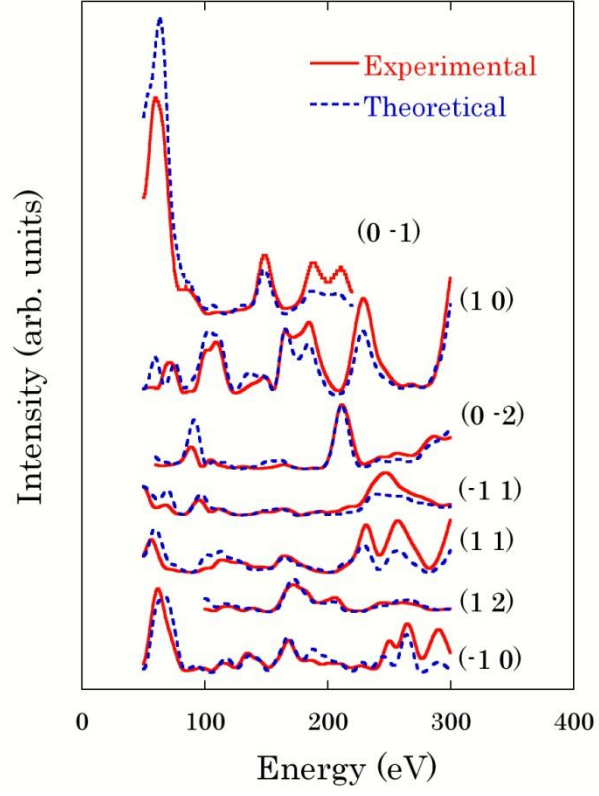


Fig. 3. Experimental and theoretical $I(E)$ curves of the best-fit Mo(112)-(1 \times 1) clean surface model.

Table 1. Structural parameters obtained for the best-fit Mo(112)-(1×1) clean surface model.

Atom (No.)	$[11\bar{2}]$ (Å)	$[\bar{1}10]$ (Å)	$[11\bar{1}]$ (Å)
Mo(1)	-1.10 ±0.02	2.23	0.91 ±0.07
Mo(2)	0.01 ±0.03	0.00	-0.05 ±0.05
Mo(3)	1.36 ±0.03	2.23	-0.97 ±0.06
Mo(4)	2.58 ±0.03	0.00	0.83 ±0.06
Mo(5)	3.90 ±0.04	2.23	-0.02 ±0.07
Mo(6)	5.17 ±0.03	0.00	-0.97 ±0.07

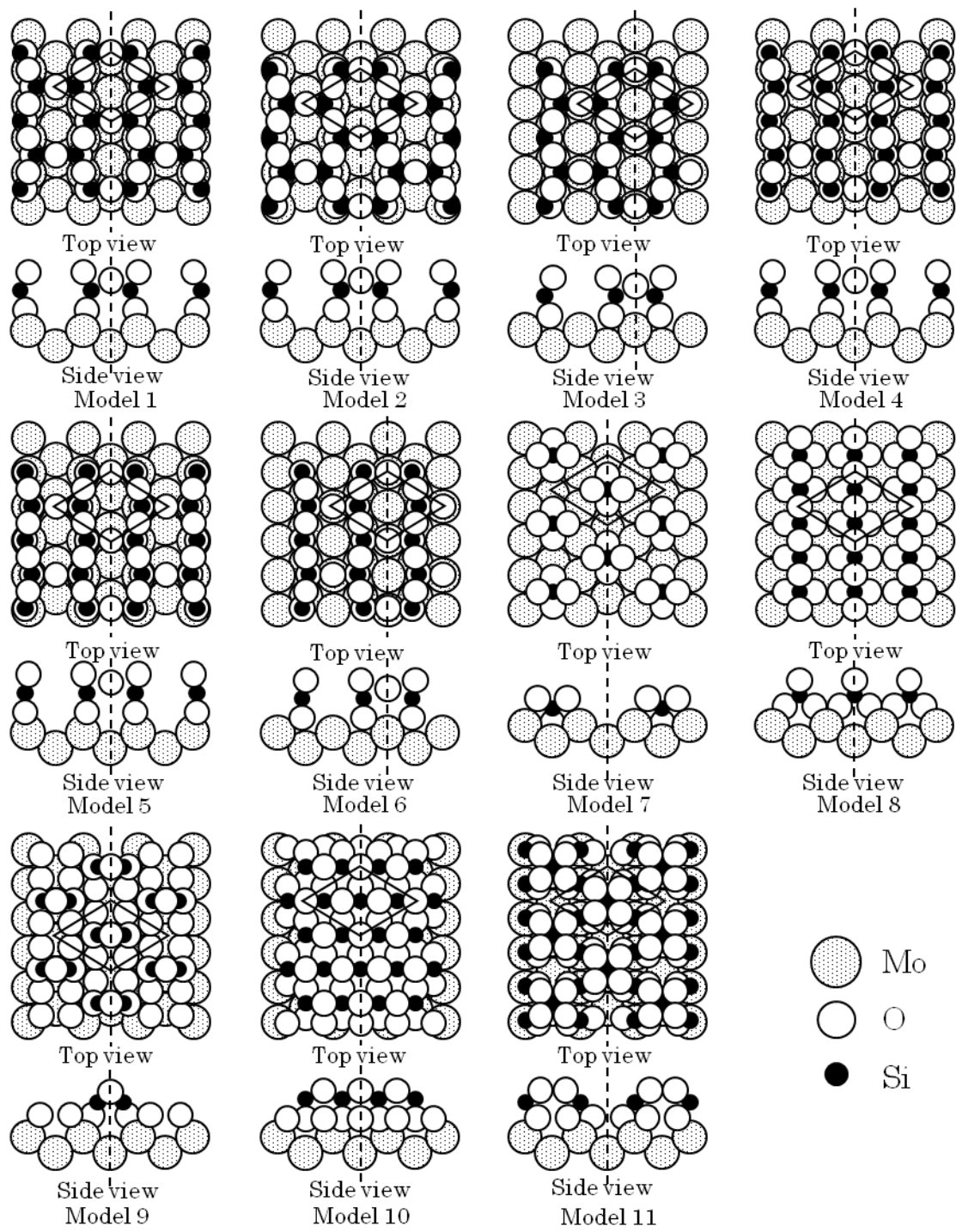


Fig. 4. Top and side views of examined structure models of the Mo(112)-c(2×2)-silica.

Table 2. Pendry's r-factors (R_p) for the models shown in Fig. 4.

Model	R_p
1	0.18
2	0.67
3	0.58
4	0.23
5	0.60
6	0.61
7	0.66
8	0.66
9	0.66
10	0.58
11	0.57

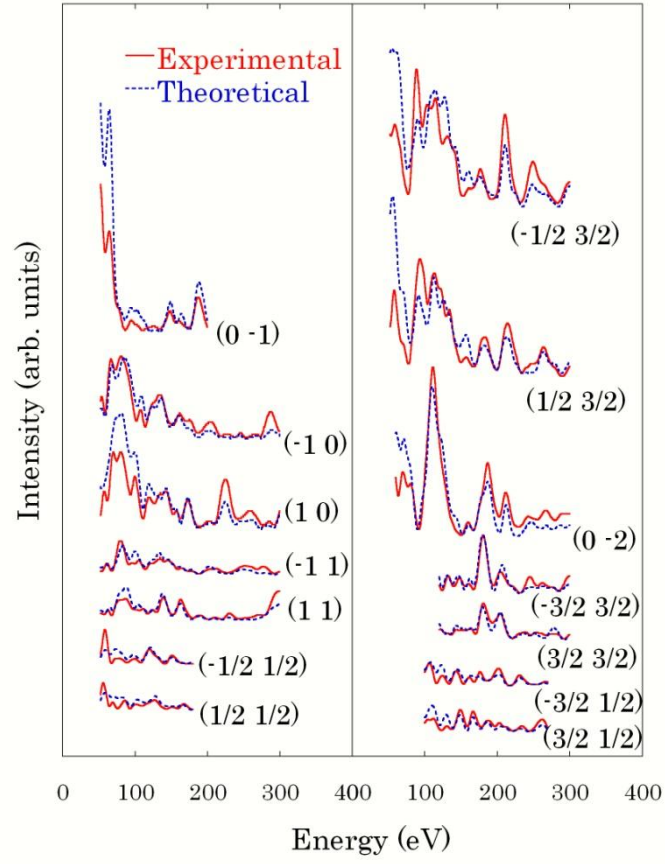


Fig. 5. Experimental and theoretical $I(E)$ curves for the best-fit structural model of the Mo(112)-c(2 \times 2)-Si₂O₅ surface.

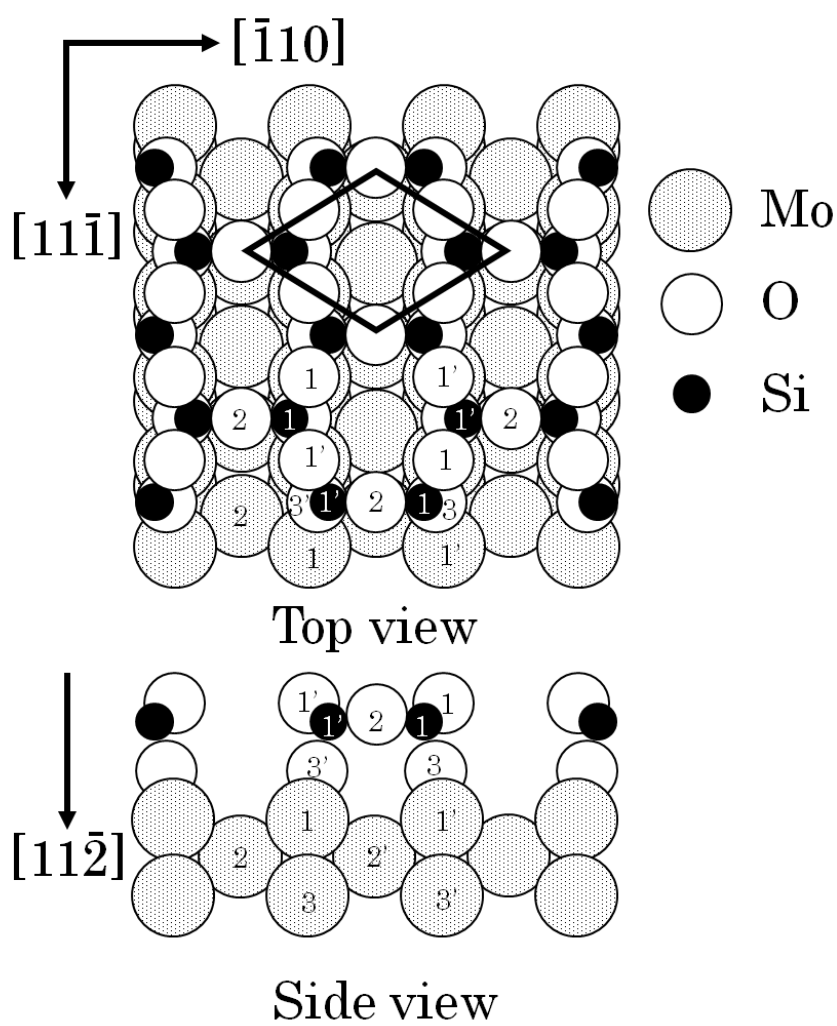


Fig. 6. Top and side views of the best-fit Mo(112)-c(2×2)-Si₂O₅ surface (model 1).

Table 3. Structural parameters obtained for the best-fit Mo(112)-c(2×2)-Si₂O₅ surface (model 1).

Atom (No.)	[11 $\bar{2}$] (Å)	[$\bar{1}$ 10] (Å)	[11 $\bar{1}$] (Å)
O(1)	-0.68 ±0.04	2.25 ±0.12	-1.32 ±0.14
O(1')	-0.68 ±0.04	2.20 ±0.12	1.41 ±0.14
O(2)	-0.29 ±0.07	0.00	-0.01 ±0.23
Si(1)	-0.03 ±0.02	1.58 ±0.09	0.01 ±0.07
Si(1')	-0.03 ±0.02	2.87 ±0.09	2.74 ±0.07
O(3)	1.56 ±0.05	1.96 ±0.12	0.04 ±0.13
O(3')	1.56 ±0.05	2.49 ±0.12	2.77 ±0.13
Mo(1)	3.18 ±0.03	2.22 ±0.05	-1.33 ±0.06
Mo(1')	3.18 ±0.03	2.23 ±0.05	1.40 ±0.06
Mo(2)	4.39 ±0.04	0.00	3.20 ±0.07
Mo(2')	4.39 ±0.02	0.00	0.50 ±0.07
Mo(3)	5.71 ±0.03	2.21 ±0.06	2.26 ±0.08
Mo(3')	5.71 ±0.03	-2.21 ±0.06	2.26 ±0.08

Table 4. Summary of bond lengths and bond angles.

	This study	Ref. [17]	α -SiO ₂ [26]	MoO ₂ [27]
Si(1)-O(1) (Å)	1.63	1.64	1.61	
Si(1)-O(1') (Å)	1.66	1.64	1.61	
Si(1)-O(2) (Å)	1.60	1.62	1.61	
Si(1)-O(3) (Å)	1.64	1.65	1.61	
Mo(1)-O(3) (Å)	2.14	2.11		2.01
Si(1)-O(1)-Si(1')	134°	133°	144°	
Si(1)-O(2)-Si(1')	162°	163°	144°	